

MIC1606PS

GaAs MMIC, L-Band, Digital 6-bit Phase Shifter, 1.0 – 1.7 GHz

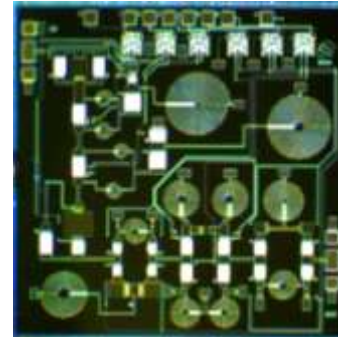
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Features

- ✓ 6-bit Phase Shift
- ✓ Phase Shift range: 5.625 degree LSB steps to 354.375 degree
- ✓ RMS attenuation error: 0.55 dB
- ✓ RMS phase error: 3.01 degree
- ✓ CMOS/TTL compatible control
- ✓ Die Size: 2.6x2.6x0.1 mm

Die Device Layout



General Description

MIC1606PS is a microwave phase shifter die and it made by the 0.5 μm length of GaAs PHEMT technology process. The die is grounded by through back metal hole.

Application

- ✓ Microwave Radio & VSAT
- ✓ Weather radars
- ✓ Point-to-Point Radio
- ✓ Ultra wide band SAT Military & Space
- ✓ Wireless infrastructure
- ✓ Mobile radio
- ✓ Cellular/4G infrastructure

Electrical Specification

Test condition unless otherwise notes: 25 °C, $V_D = -5\text{ V}$, $I_D = 25\text{ mA}$, continuous mode.

Parameter	Typ.	Units
Frequency Range (Δf)	1÷1.7	GHz
Insertion Loss (S21), Reference Level	5.60	dB
Loss Flatness ($\Delta S21$)	±1.15	dB
Phase Shift Step Size	5.625	degree
Phase Shift Range	354.375	degree
RMS Attenuation Error	0.55	dB
Max Attenuation Error	1.7	dB
RMS Phase Error	3.01	degree
Max Phase Error	±5.625	degree
Input Voltage Standing Wave Ratio, All states	2.75	-
Output Voltage Standing Wave Ratio, All states	2.32	-
Voltage Control Low (V_{CTRL0})	0÷0.8	V
Voltage Control High (V_{CTRL1})	3.3÷5	V
Supply Voltage (V_D)	-5	V
Supply Current (I_D)	25	mA

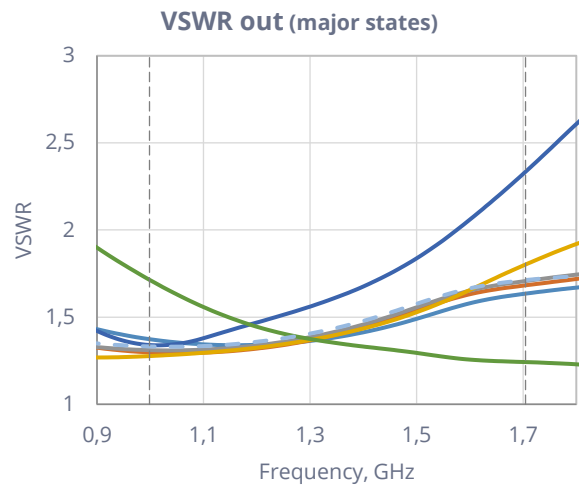
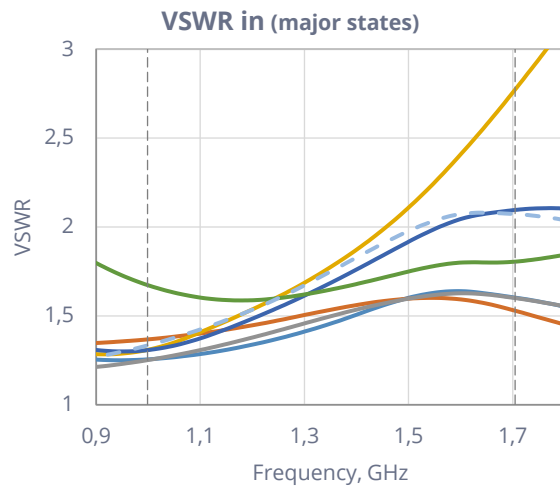
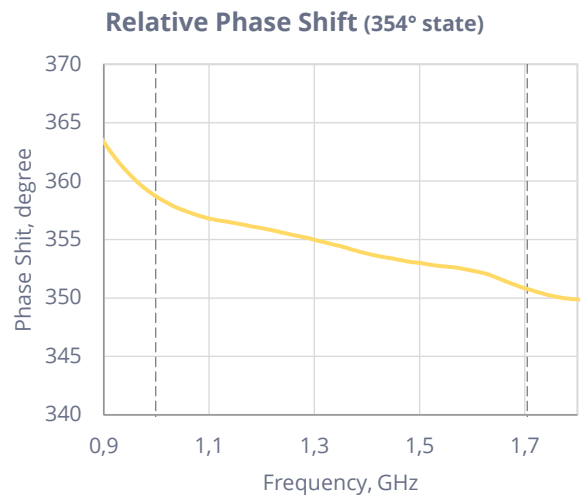
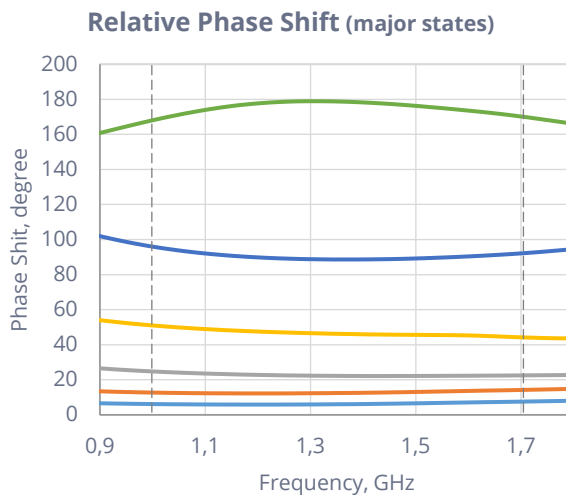
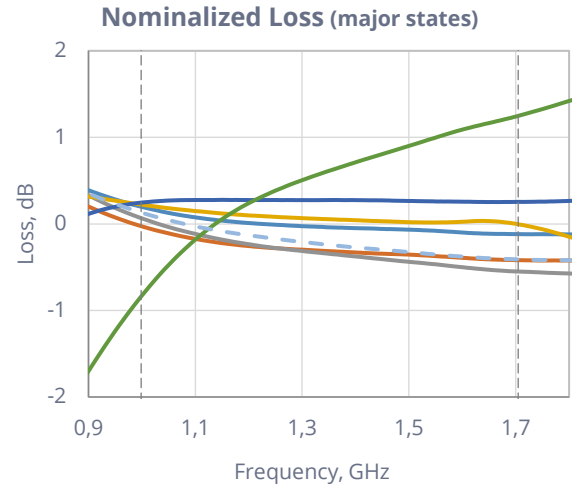
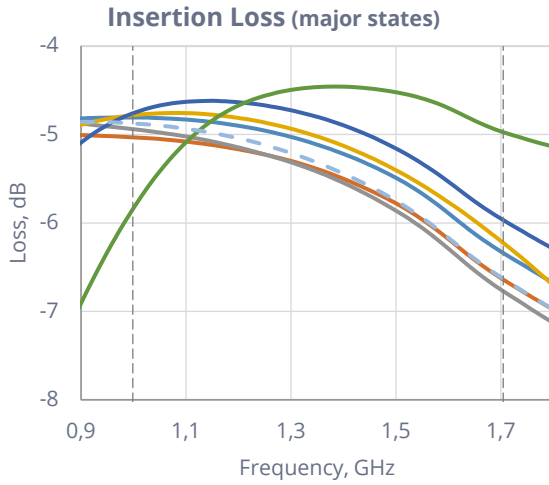
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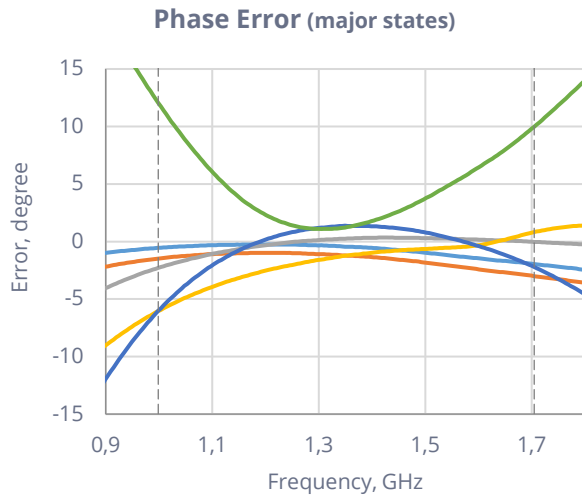
Digital Step Phase Shifter Measurements (continuous mode)



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Absolute Maximum Ratings

Parameter	Absolute Maximum	Unit
Gate Voltage (V_g)	-5.5	V
Input Power (P_{in})	+20	dBm
Storage Temperature	-70 to +95	°C
Operating Temperature	-60 to +85	°C
Channel Temperature	+175	°C

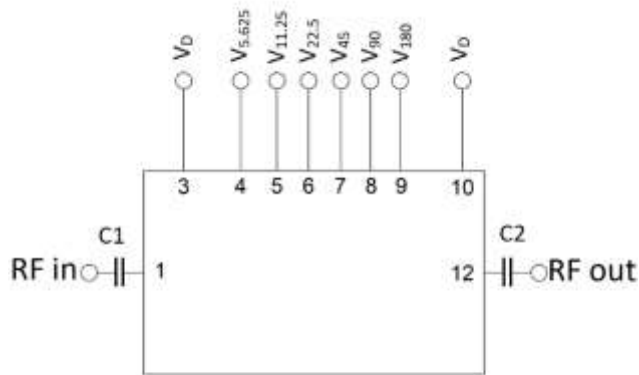
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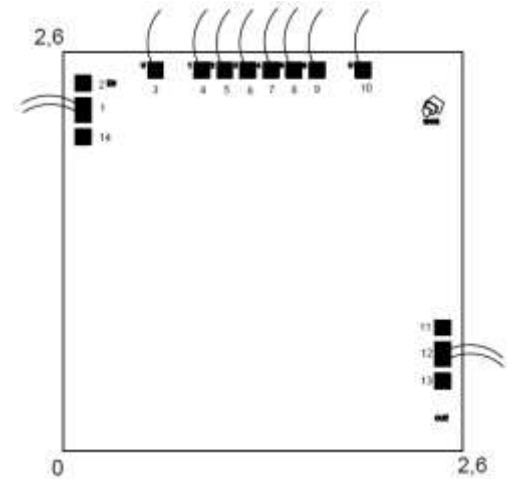
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Application Circuit



Die Outline



Additional Components

Reference Designator	Components
C1-2	Caps: 100 pF, 600S101JT250X

Pad Diagram & Dimension (units in mm)

N	Function	Origin		Size	
		X	Y	X	Y
1	RF in	0.12	1.79	0.10	0.16
2	GND	0.12	1.94	0.10	0.10
3	V _D	0.72	2.46	0.10	0.10
4	V _{5.625}	1.02	2.46	0.10	0.10
5	V _{11.25}	1.17	2.46	0.10	0.10
6	V _{22.5}	1.32	2.46	0.10	0.10
7	V ₄₅	1.47	2.46	0.10	0.10
8	V ₉₀	1.62	2.46	0.10	0.10
9	V ₁₈₀	1.77	2.46	0.10	0.10
10	V _D	2.07	2.46	0.10	0.10
11	GND	3.18	1.94	0.10	0.10
12	RF out	3.18	1.79	0.10	0.16
13	GND	3.18	1.64	0.10	0.10
14	GND	0.12	1.64	0.10	0.10

Logic Truth Table – Major States

Phase Shift (degree)	Digital Control Input					
	V _{5.625}	V _{11.25}	V _{22.5}	V ₄₅	V ₉₀	V ₁₈₀
0 (Reference)	Low	Low	Low	Low	Low	Low
5.625	High	Low	Low	Low	Low	Low
11.25	Low	High	Low	Low	Low	Low
22.5	Low	Low	High	Low	Low	Low
45.0	Low	Low	Low	High	Low	Low
90.0	Low	Low	Low	Low	High	Low
180.0	Low	Low	Low	Low	Low	High
354.375	High	High	High	High	High	High

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Handling and Assembly Information

CAUTION! - This MMIC Products contain gallium arsenide (GaAs) which can be hazardous to the human body and the environment. For safety, observe the following procedures:

- *Do not ingest.*
- *Do not alter the form of this product into a gas, powder, or liquid through burning, crushing, or chemical processing as these by-products are dangerous to the human body if inhaled, ingested, or swallowed.*
- *Observe government laws and company regulations when discarding this product. This product must be discarded in accordance with methods specified by applicable hazardous waste procedures.*

Life Support Policy - This product is not authorized for use as critical components in life support devices or systems. As used herein: (1) Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user. (2) A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



ESD - Gallium Arsenide (GaAs) devices are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic containers, which should be opened in cleanroom conditions at an appropriately grounded antistatic workstation. Devices need careful handling using correctly designed collets, vacuum pickups or, with care, sharp tweezers.

Die Attachment - GaAs Products are 0.100 mm (0.004") thick and have vias through to the backside to enable grounding to the circuit. Microstrip substrates should be brought as close to the die as possible (<100um is good). The mounting surface should be clean and flat. If using conductive epoxy, recommended epoxies are Namics SK70N, Ablestick 84-1LMI or 84-1LMI cured in a nitrogen atmosphere per manufacturer's cure schedule. Apply epoxy sparingly to avoid getting any on to the top surface of the die. An epoxy fillet should be visible around the total die periphery. If eutectic mounting is preferred, then a fluxless gold-tin (AuSn) preform, approximately 0.001 thick, placed between the die and the attachment surface should be used. A die bonder that utilizes a heated collet and provides scrubbing action to ensure total wetting to prevent void formation in a nitrogen atmosphere is recommended.

Wire Bonding - Windows in the surface passivation above the bond pads are provided to allow wire bonding to the die's gold bond pads. The recommended wire bonding procedure uses 0.076 mm x 0.013 mm (0.003" x 0.0005") 99.99% pure gold ribbon with 0.5-2% elongation to minimize RF port bond inductance. Gold 0.025 mm (0.001") diameter wedge or ball bonds are acceptable for DC Bias connections. Aluminum wire should be avoided. Thermo-compression bonding is recommended though thermosonic bonding may be used providing the ultrasonic content of the bond is minimized. Bond force, time and ultrasonics are all critical parameters. Bonds should be made from the bond pads on the die to the package or substrate. All bonds should be as short as possible.